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HOZIRGI TADQIQOTLARI	<p>1.Kutliev U.O., Karimov M.K., Kuryozov F.O., Otabaeva K.U. Analysis of InGaP(001) surface by the low energy ion scattering spectroscopy // Journal of Physics: Conference Series, 2021. – Volume. 1889. (№3 Scopus, IF = 0.7), (01.00.00; №16)</p> <p>2.Karimov M.K., Kutliev U.O., Otabaeva K.U., Otabaev M.U. Angular Distributions of Scattered Ne and Ar Ions at the Grazing Incidence on the InGaP (001) <110> Surface // Journal of Nano- and Electronic Physics, 2020. – Volume.12, No.5. 05032(4pp). (№3 Scopus, IF = 1.1)</p> <p>3.Kutliev U.O., Karimov M.K., Otaboiev M.U. Orientation Effects during Scattering of Ar+ Ions from the InP(001) Surface under Grazing-Angle Ion Bombardment // Inorganic Materials: Applied Research, 2020. – V..11, No.3. – pp. 503–506. (№3 Scopus, IF = 1.1)</p> <p>4.Karimov M.K., Kutliev U.O., Ismailov Sh.K., Otabaev M.U. Low Energy Ar+ Ion Scattering on InGaP(001) Surface // e-Journal of Surface Science and Nanotechnology, 2020. – Volume.18, – pp.164 – 167. (№3 Scopus, IF = 1.0)</p> <p>5.Karimov M.K., Matchonov Kh.J., Otaboieva K.U., Otaboiev M.U. Computer Simulation of Scattering Xe+ Ions from InP(001)<110> Surface at Grazing Incidence // e-Journal of Surface Science and Nanotechnology, 2019. V.17, pp.179-183. (№3 Scopus, IF = 0.9)</p> <p>6.Каримов М.К., Кутлиев У.О., Отабоева К.У, Отабоев М.У. Вычисление неупругих потерь энергии при ионно – атомном столкновении // Агентство по интеллектуальной собственности Республики Узбекистан официальный бюллетень, 2019. DGU 06100. 3(215). – С.320.</p> <p>7.Kutliev U., Karimov M., Sadullaeva B., Otaboiev M. Investigation of the ion scattering process from the A3B5 semiconductors by the computer simulation method // COMPUSOFT, An international journal of advanced computer technology, 2018. – Volume. 7, No.4. – pp. 2749 – 2751. (№3 Scopus)</p> <p>8.Karimov M.K., Tangriberganov I.U., Qurbanov M.K., KutlievU.O., Otaboiev M. U. Angular and energy distributions of low – energy argon ions at the scattering from АИIBV semiconductor surface // Actual problems of modern science, education and training in the region, 2018. – Volume. 3, No.2. – pp. 5–15. (01.00.00; №10)</p> <p>9.Кутлиев У.О., Каримов М.К., Отабоев М.У., Балтаева М.М. Определения энергии одно – идвукратно рассеянных ионов поверхностей твёрдого тела // Агентство по интеллектуальной собственности Республики Узбекистан официальный бюллетень, 2018. DGU 05605. 9(209). – С.275.</p>